

# **FQD16N25C** 250V N-Channel MOSFET

### **Features**

- \* 16A, 250V,  $R_{DS(on)}$  = 0.27 $\Omega$  @V<sub>GS</sub> = 10 V \* Low gate charge ( typical 41 nC)
- Low Crss (typical 68 pF)
- · Fast switching
- 100% avalanche tested
- · Improved dv/dt capability
- RoHS compliant





## Description

These N-Channel enhancement mode power field effect transistors are produced using Fairchild's proprietary, planar stripe, DMOS technology.

This advanced technology has been especially tailored to minimize on-state resistance, provide superior switching performance, and withstand high energy pulse in the avalanche and commutation mode. These devices are well suited for high efficiency switching DC/DC converters, switch mode power supplies, DC-AC converters for uninterrupted power supplies and motor controls.

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### **Absolute Maximum Ratings**

Symbol	Parameter		FQD16N25C	Units
V <sub>DSS</sub>	Drain-Source Voltage		250	V
I <sub>D</sub>	Drain Current - Continuous ( $T_C = 25^{\circ}C$ )		16	А
	- Continuous (T <sub>C</sub> = 100°C)		10.1	А
I <sub>DM</sub>	Drain Current - Pulsed	(Note 1)	64	А
V <sub>GSS</sub>	Gate-Source Voltage		± 30	V
E <sub>AS</sub>	Single Pulsed Avalanche Energy	(Note 2)	432	mJ
I <sub>AR</sub>	Avalanche Current	(Note 1)	16	А
E <sub>AR</sub>	Repetitive Avalanche Energy	(Note 1)	160	mJ
dv/dt	Peak Diode Recovery dv/dt	(Note 3)	5.5	V/ns
P <sub>D</sub>	Power Dissipation ( $T_C = 25^{\circ}C$ )		160	W
	- Derate above 25°C		1.28	W/°C
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature Range		-55 to +150	°C
TL	Maximum lead temperature for soldering purposes, 1/8" from case for 5 seconds		300	°C

### **Thermal Characteristics**

Symbol	Parameter	FQD16N25C	Units	
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case	0.78	°C/W	
$R_{\thetaJA}$	Thermal Resistance, Junction-to-Ambient	110	°C/W	

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### Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FQD16N25C	FQD16N25CTM	D-PAK	380mm	16mm	2,500
FQD16N25C	FQD16N25CTF	D-PAK	380mm	16mm	2,000

### Electrical Characteristics T<sub>C</sub> = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Charac	teristics					
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0 V, I <sub>D</sub> = 250 μA	250			V
$\Delta BV_{DSS}/\Delta T_J$	Breakdown Voltage Temperature Coefficient	$I_D$ = 250 µA, Referenced to 25°C		0.31		V/°C
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{DS}$ = 250 V, $V_{GS}$ = 0 V			10	μA
		$V_{DS}$ = 200 V, $T_{C}$ = 125°C			100	μA
I <sub>GSSF</sub>	Gate-Body Leakage Current, Forward	$V_{GS}$ = 30 V, $V_{DS}$ = 0 V			100	nA
I <sub>GSSR</sub>	Gate-Body Leakage Current, Reverse	$V_{GS}$ = -30 V, $V_{DS}$ = 0 V			-100	nA
On Charact	teristics					
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS}$ = $V_{GS}$ , $I_D$ = 250 $\mu$ A	2.0		4.0	V
R <sub>DS(on)</sub>	Static Drain-Source On-Resistance	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 8A		0.22	0.27	Ω
9 <sub>FS</sub>	Forward Transconductance	V <sub>DS</sub> = 40 V, I <sub>D</sub> =8 A (Note 4)		10.5		S
Dynamic Cl	haracteristics					
C <sub>iss</sub>	Input Capacitance	$V_{DS}$ = 25 V, $V_{GS}$ = 0 V,		830	1080	pF
C <sub>oss</sub>	Output Capacitance	f = 1.0 MHz		170	220	pF
C <sub>rss</sub>	Reverse Transfer Capacitance			68	89	pF
Switching C	Characteristics					
t <sub>d(on)</sub>	Turn-On Delay Time	V <sub>DD</sub> = 125 V, I <sub>D</sub> = 16A,		15	40	ns
t <sub>r</sub>	Turn-On Rise Time	R <sub>G</sub> = 25 Ω		130	270	ns
t <sub>d(off)</sub>	Turn-Off Delay Time	-		135	280	ns
t <sub>f</sub>	Turn-Off Fall Time	(Note 4, 5)		105	220	ns
Qg	Total Gate Charge	V <sub>DS</sub> = 200 V, I <sub>D</sub> = 16A,		41	53.5	nC
Q <sub>gs</sub>	Gate-Source Charge	V <sub>GS</sub> = 10 V		5.6		nC
Q <sub>gd</sub>	Gate-Drain Charge	(Note 4, 5)		22.7		nC
Drain-Sour	ce Diode Characteristics and Maximum Ratings	5				
I <sub>S</sub>	Maximum Continuous Drain-Source Diode Fo	rward Current			16	Α
I <sub>SM</sub>	Maximum Pulsed Drain-Source Diode Forward Current				64	Α
V <sub>SD</sub>	Drain-Source Diode Forward Voltage	V <sub>GS</sub> = 0 V, I <sub>S</sub> = 16 A			1.5	V
t <sub>rr</sub>	Reverse Recovery Time	V <sub>GS</sub> = 0 V, I <sub>S</sub> = 16 A,		260		ns
Q <sub>rr</sub>	Reverse Recovery Charge	$dI_{F}/dt = 100 \text{ A}/\mu \text{s}$ (Note 4)		2.47		μC

NOTES:

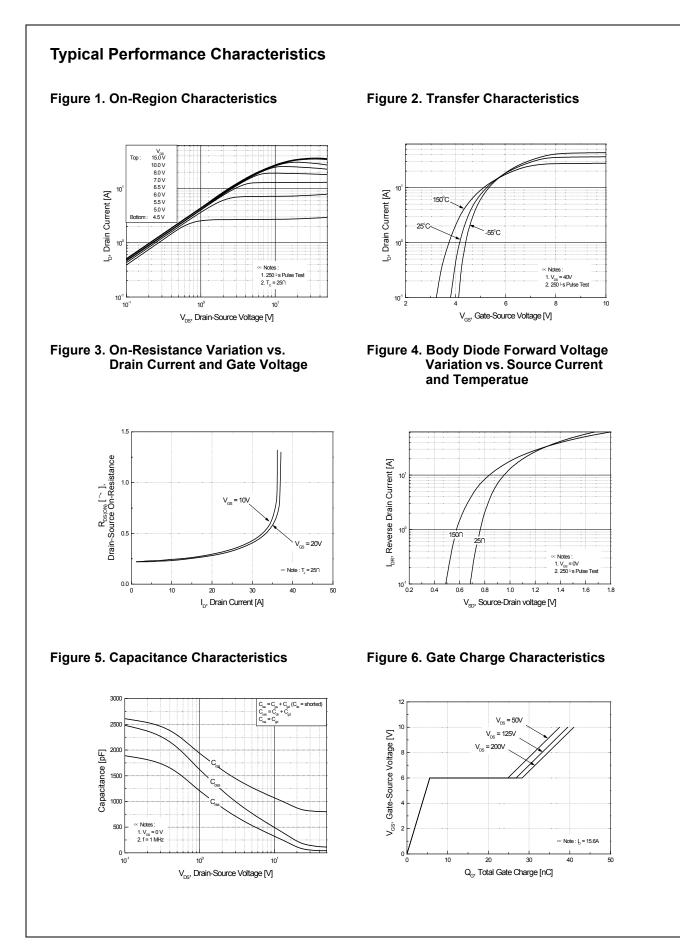
1. Repetitive Rating : Pulse width limited by maximum junction temperature

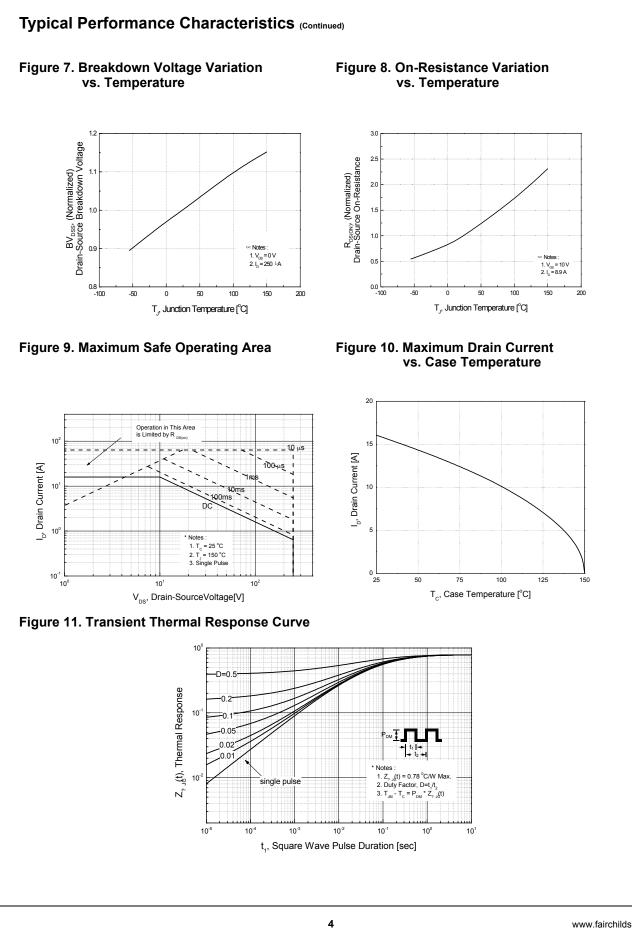
2. L = 2.7mH, I<sub>AS</sub> = 16A, V<sub>DD</sub> = 50V, R<sub>G</sub> = 25  $\Omega,$  Starting T<sub>J</sub> = 25°C

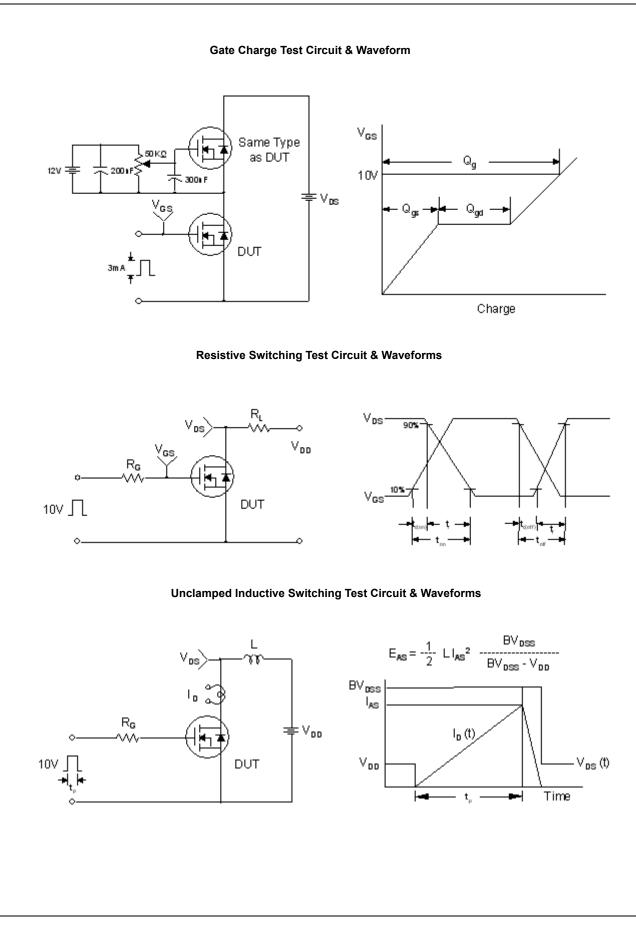
3. I\_{SD} \leq 16A, di/dt  $\leq$  300A/µs, V\_{DD}  $\leq$  BV\_{DSS,} Starting ~T\_J = 25°C

4. Pulse Test : Pulse width  $\leq 300 \mu s,$  Duty cycle  $\leq 2\%$ 

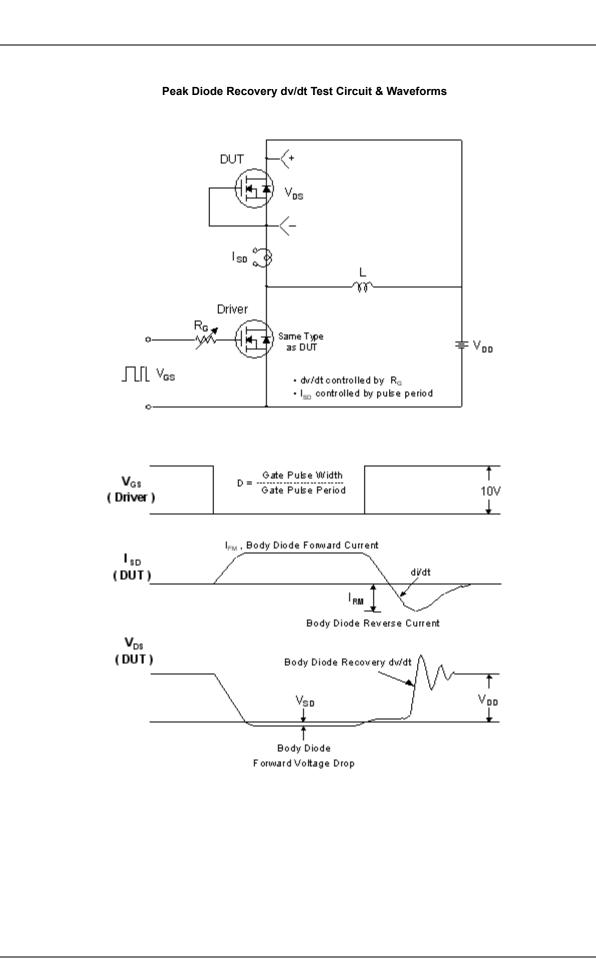
5. Essentially independent of operating temperature

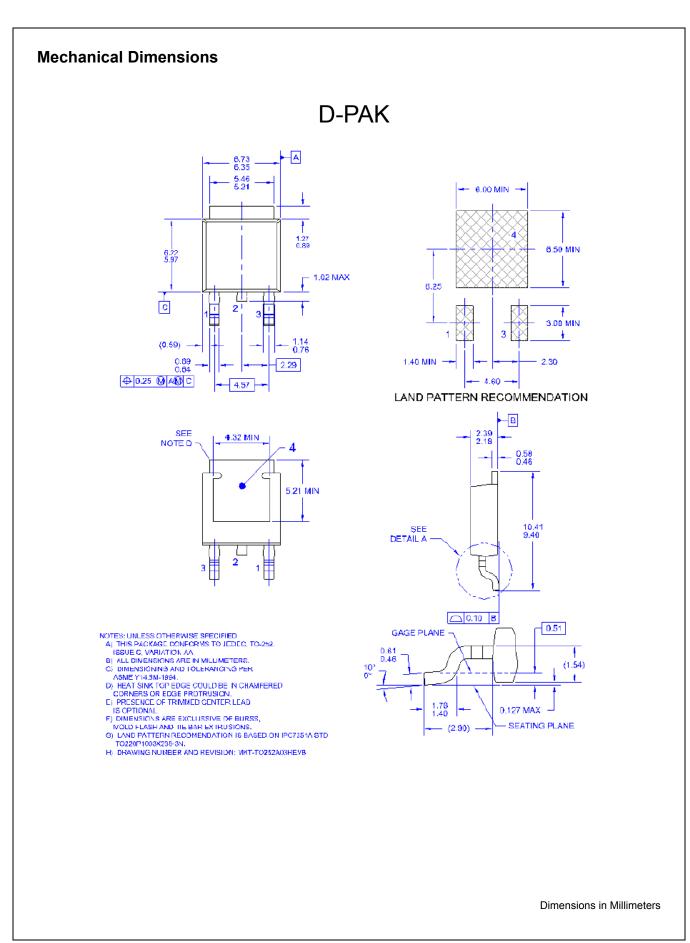






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